

S5D25170A/S5D25170F 1700V SIC POWER SCHOTTKY RECTIFIERS

Description




This 1700V 25A diode is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S5D25170A/S5D25170F is ideal for energy sensitive high frequency applications in challenging environments.

Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- “-A” is an AEC-Q101 qualified device
- Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

<p>S5D25170A</p> 	<p>S5D25170F</p> 
<p>TO-220AC (TO-220-2)</p>	<p>ITO-220AC (TO-220MF-2L)</p>
	

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	1700	V
Average Rectified Forward Current	$I_{F(AV)1}$	$T_c=25^{\circ}\text{C}$	66	A
	$I_{F(AV)2}$	$T_c=146^{\circ}\text{C}$	25	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM1}	10ms, Half Sine pulse, $T_c=25^{\circ}\text{C}$	280	A
	I_{FSM2}	10ms, Half Sine pulse, $T_c=110^{\circ}\text{C}$	210	A
Repetitive Peak Forward Surge Current	I_{FRM1}	10 ms, Half Sine pulse, $T_c=25^{\circ}\text{C}$	168	A
	I_{FRM2}	10 ms, Half Sine pulse, $T_c=110^{\circ}\text{C}$	122	A
Power Dissipation	P_{tot1}	$T_c=25^{\circ}\text{C}$	394.7	W
	P_{tot2}	$T_c=110^{\circ}\text{C}$	171.1	W

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 25A, Pulse, $T_J = 25^{\circ}\text{C}$	1.55	1.8	V
	V_{F2}	@ 25A, Pulse, $T_J = 175^{\circ}\text{C}$	2.5	3.0	V
Reverse Current*	I_{R1}	@ $V_R = \text{rated } V_R, T_J = 25^{\circ}\text{C}$	1	10	μA
	I_{R2}	@ $V_R = \text{rated } V_R, T_J = 175^{\circ}\text{C}$	20	200	μA
Junction Capacitance	C_{T1}	$V_R=0\text{V}, f=1\text{MHz}, T_J=25^{\circ}\text{C},$	2400	-	pF
	C_{T2}	$V_R=1700\text{V}, f=1\text{MHz}, T_J=25^{\circ}\text{C},$	126	-	pF
Reverse Recovery Charge	Q_c	$I_F = 25\text{A}, di/dt = 200\text{A}/\mu\text{s}$ $V_R = 1700\text{V}, T_J = 25^{\circ}\text{C}$	296.59	-	nC
Capacitance Stored Energy	E_c	$V_R = 1700\text{V}, T_J = 25^{\circ}\text{C}$	308.55	-	μJ

* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	S5D25170A	S5D25170F	Units
Junction Temperature	T_J	-55 to +175		°C
Storage Temperature	T_{stg}	-55 to +175		°C
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	0.38	2.9	°C/W

Ordering Information

Device	Package	Shipping
S5D25170A	TO-220AC(TO-220-2)	50pcs / tube
S5D25170F	ITO-220AC(TO-220MF-2L)	50pcs / tube

Ratings and Characteristics Curves

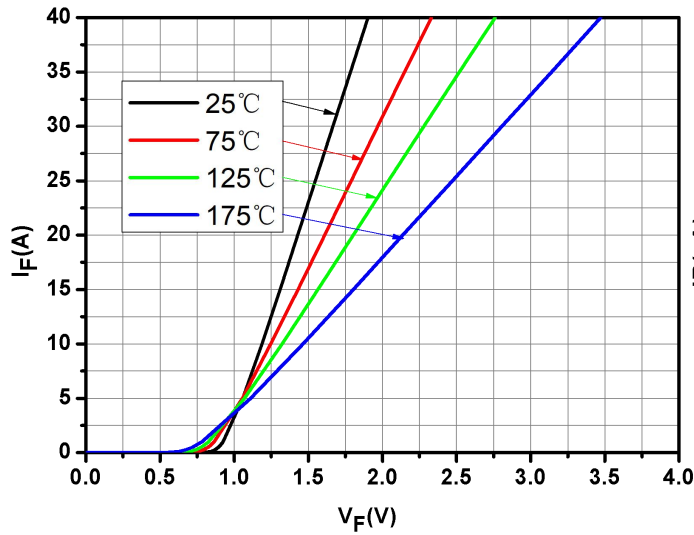


Fig.1-Typical Forward Voltage Characteristics

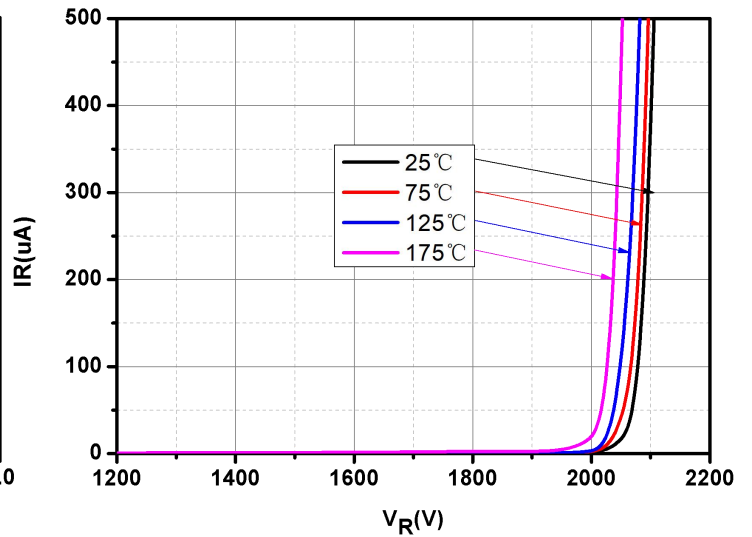


Fig.2-Typical Reverse Characteristics

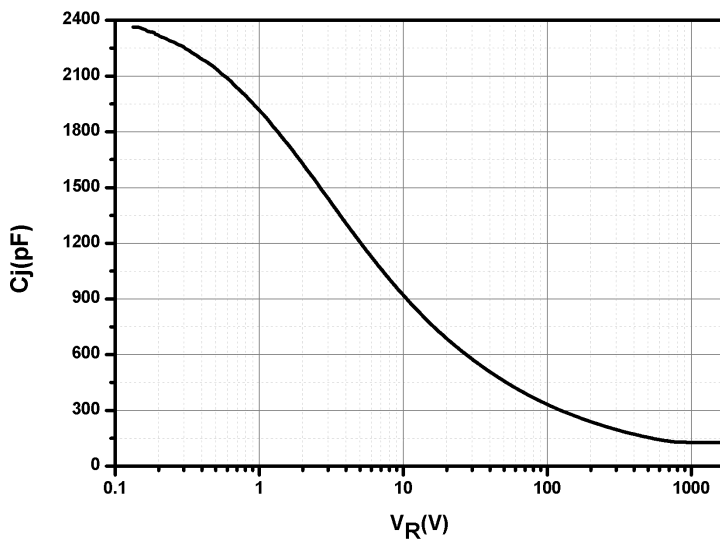


Fig.3-Capacitance vs. Reverse Voltage

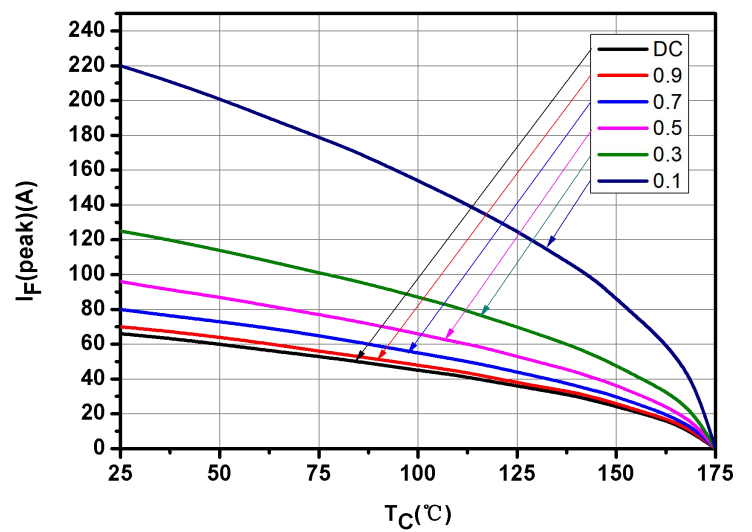


Fig.4-Current Derating

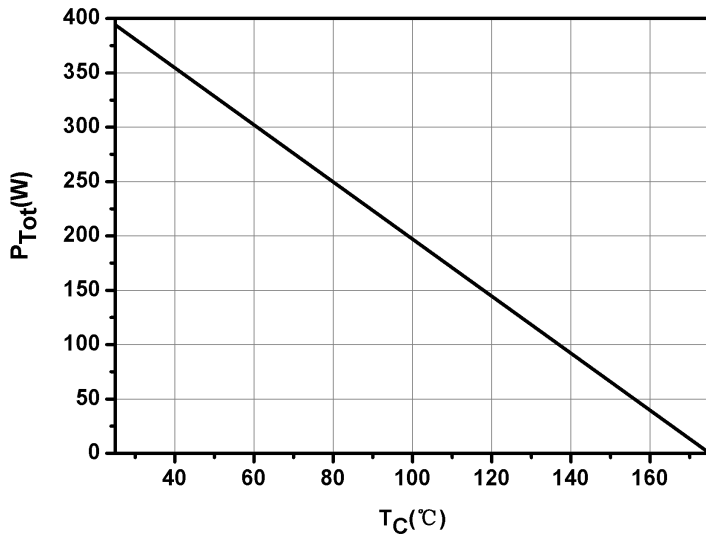


Fig.5-Power Derating

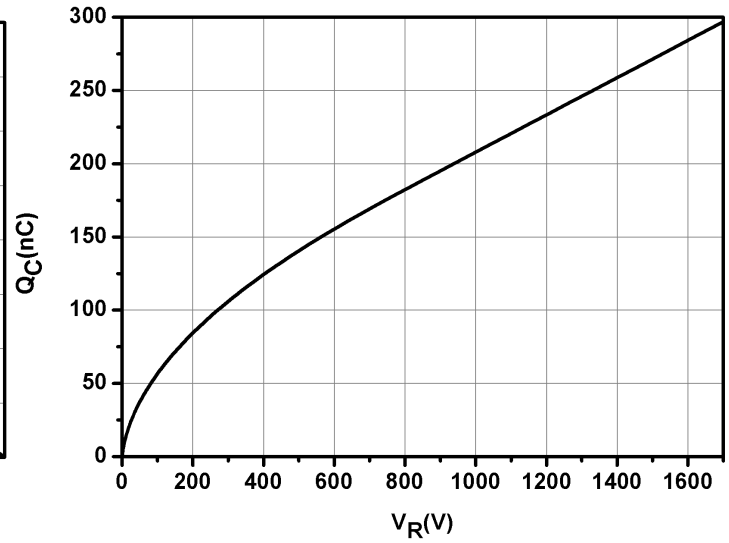


Fig.6-Total Capacitance Charge vs. Reverse Voltage

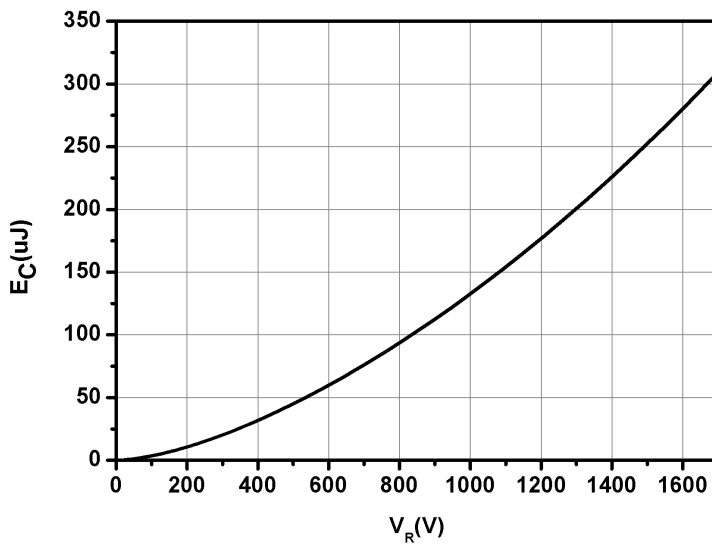
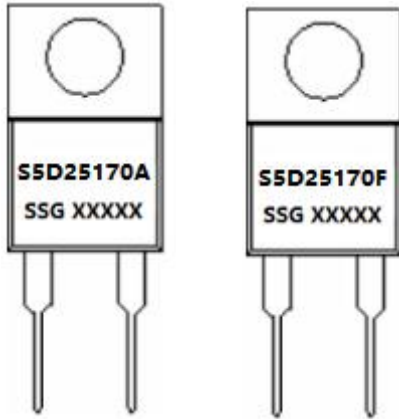


Fig.7-Capacitance Stored Energy

Marking Diagram

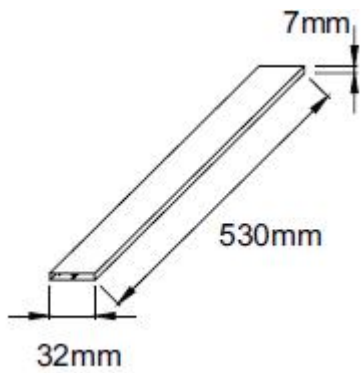


Where XXXXX is YYWWL

S5D = Device Type
A/F = Package type
25 = Forward Current (25A)
170 = Reverse Voltage (1700V)
SSG = SSG
YY = Year
WW = Week
L = Lot Number

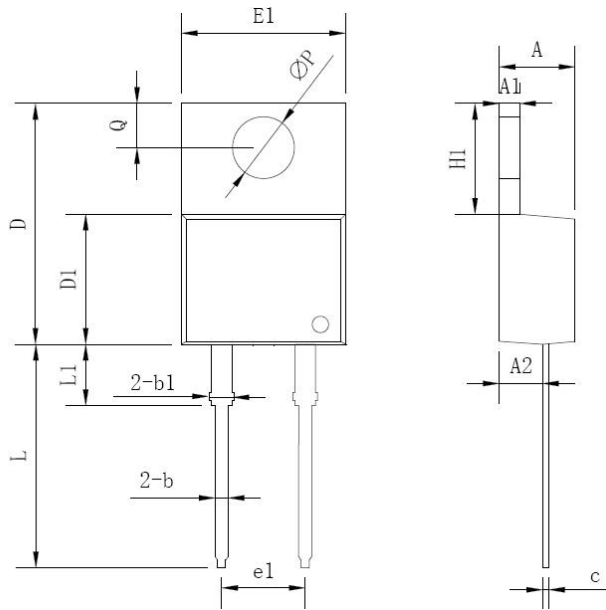
Cautions: Molding resin
Epoxy resin UL:94V-0

Tube Specification(TO-220-2)



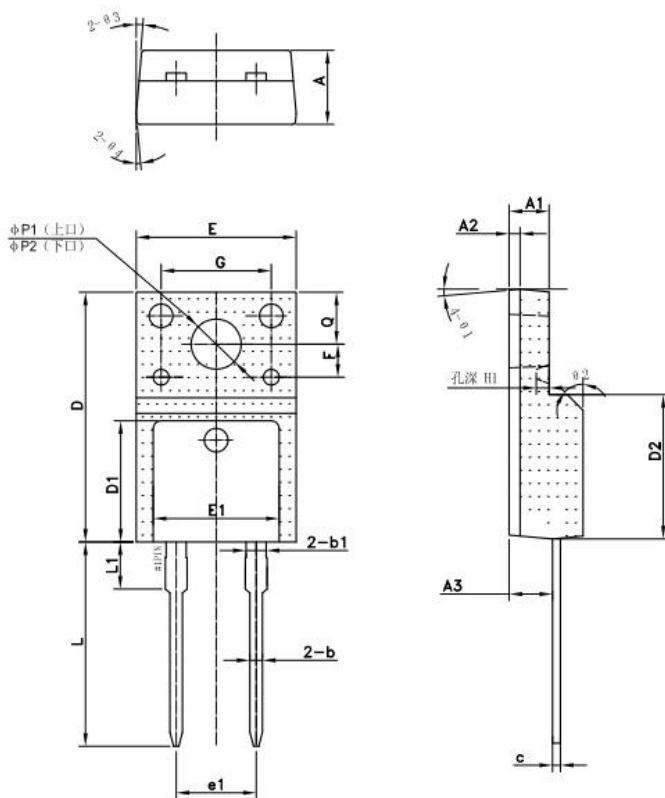
(TO-220-2/TO-220-F2)

Mechanical Dimensions TO-220AC(TO-220-2)



Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	3.56	-	4.83
A1	0.51	-	1.40
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
c	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E1	9.65	10.16	10.67
e1	-	5.08	-
H1	5.84	-	6.86
L	12.70	-	14.73
L1	-	-	6.35
ΦP	-	3.56	-
Q	2.54	-	3.43

Mechanical Dimensions ITO-220AC(TO-220MF-2L)



Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
A	4.50	4.70	4.90
A1	2.34	2.54	2.74
A2		0.70	
A3	2.56	2.76	2.96
b	0.70	0.80	0.95
b1		1.28	
c	0.45	0.50	0.65
D	15.67	15.87	16.07
D1		7.70	
D2		9.12	
E	9.96	10.16	10.36
E1		8.00	
e1		5.08	
F		2.1	
G		7	
H1		0.81	
L	12.48	12.98	13.20
L1		2.93	
4>P1 (上口)	2.98	3.18	3.38
4>P2 (下口)	3.20	3.40	3.60
Q	3.10	3.30	3.50
e 1		5°	
02		45°	
03		5°	
e 4		5°	



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